



300mA Low Noise CMOS LDO

SOT-25

Pin Definition:





- 3. Enable
- 4. Bypass
- 5. Output

DFN 2x2



Pin Definition:

- 1. Input
- 2. N/C
- 3. Output
- 4. N/C
- 5. Ground
- 6. Enable

General Description

The TS9007 series is 300mA ultra-low-noise LDO especially designed for battery-power RF and wireless applications. The TS9007 regulator achieves a low 450mV dropout at 300mA load current of 3.3V output, ultra-low output voltage noise of 15uVrms and PSRR of 57dB at 1KHz.

The TS9007 regulators are also optimized to work with low-ESR and low cost ceramic capacitors reducing the amount of board space critical in hand-held devices. The TS9007 requires only 0.47uF output capacitor for stability with and load. The TS9007 consumes less than 1uA in shutdown mode.

Features

- 450mV Dropout at 300mA load (3.3V)
- Low quiescent current: 90μA
- Output voltage ±2%
- Internal current limit and thermal shutdown
- Power saving shutdown mode (<1uA)
- Only need input and output capacitors
- Build-In internal Soft-Start
- Output short-circuit current limit protection

Applications

- Palmtops, PDA and Notebook Computers
- DSC, Handset Camera Modules
- PCMCIA Cards, PC Cameras
- USB Based Portable Devices (MPS, PMP)
- GSM/GPRS/3G RF Transceiver Modules

Ordering Information

Part No.	Package	Packing		
TS9007 <u>x</u> CX5 RF	SOT-25	3Kpcs / 7" Reel		
TS9007xCQ RF	DFN 2x2	3Kpcs / 7" Reel		

Note: Where **x** denotes voltage option, available are

1= 1.2V

A= 1.5V

D= 1.8V

K= 2.5V

M= 2.7V

N= 2.8V

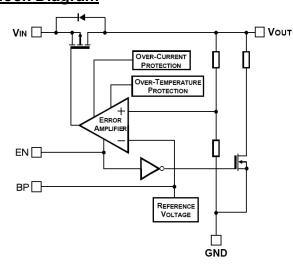
O= 2.9V

P= 3.0V

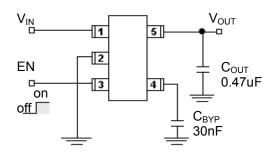
S= 3.3V

Contact factory for additional voltage options.

Block Diagram



Typical Application Circuit



EN (Pin 3) may be connected directly to V_{IN} (Pin1) Low noise operation: C_{BYP} =30nF, C_{OUT} >0.47uF Basic operation: C_{BYP} =not used, C_{OUT} >1uF





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Absolute Maximum Rating

	Symbol	Limit	Unit
	V _{IN}	-0.3 ~ +7	V
Input Supply Voltage (Recommended)			V
Output Short-Circuit Duration			
SOT-25	P _D	300	mW
DFN 2x2		500	IIIVV
SOT-25	Δ	250	°C/W
DFN 2x2	OJA	165	C/VV
	TJ	+150	°C
Storage Temperature Range			°C
	DFN 2x2 SOT-25	V _{IN} V _{OPR} SOT-25 DFN 2x2 SOT-25 DFN 2x2 Θ _{JA}	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$

Notes: Stress above the listed absolute rating may cause permanent damage to the device.

Electrical Characteristics ($T_A = 25^{\circ}C$, $V_{IN} = (V_{OUT} + 1V)$, $C_{IN} = C_{OUT} = 0.47 \text{uF}$, $V_{EN} = V_{IN}$, unless otherwise noted.)

Parameter	Conditions	Conditions		Тур	Max	Unit	
Output Voltage	$V_{IN} = V_O + 1V, I_O = 10 \text{mA}$		-2.0		+2	%	
Output Current Limit	Short-circuit output			200		mA	
Maximum Output Current	V _{IN} =Vo+1V,		300			mA	
Line Regulation	V _{IN} =(V _{OUT} +1V) to 6V, I _O =10mA			0.3		%/V	
Load Degulation	V _{IN} =Vo+1V, 1mA≤IL≤300mA	V _{OUT} ≥2.5V		0.2	1.0	%	
Load Regulation	V _{IN} =Vo+1V, 1mA≤IL≤200mA	V _{OUT} <2.5V		0.2	1.0		
Dranaut Valtaga	Io=300mA, V _{OUT} =Vo - 2%	V _{OUT} ≥2.5V		500	600	mV	
Dropout Voltage	Io=200mA, V _{OUT} =Vo - 2%	V _{OUT} <2.5V		800	1000		
Shutdown Supply Current	itdown Supply Current EN=0V			0.01		uA	
Ground Pin Current	ound Pin Current Io=0mA			90	150	uA	
	f=100Hz, lo=1mA			60		dB	
Ripple Rejection (PSRR)	f=1KHz, lo=1mA			57			
	f=10Hz, lo=1mA		45				
Output Naiga	lo=10mA, f=10Hz to 100kHz, Bypass = 0nF			45		\ /rm.o	
Output Noise	lo=10mA, f=10Hz to 100kHz, Bypass = 30nF			15		uVrms	
Shutdown Exit Delay (note 2)	, ·			45	300	uS	
EN Logic Low Level	V _{IN} =2.0V to 5.5V				0.4		
EN Logic High Level	V _{IN} =2.0V to 5.5V		1.5		VIN	V	
N Input Bias Current V _{IN} =2.0V to 5.5V						uA	
Thermal Shutdown	Shutdown Temperature			160		°C	
Thermal Shutdown Hysteresis				20		°C	

Notes:

b. Time needed for $V_{\text{OUT}}\,\text{to reach}\,\,90\%$ of final value

a. The drop out voltage varies depending on output voltage selection. Dropout is defined as V_{IN} - V_{OUT} when V_{OUT} is 100mV below V_{OUT} where V_{IN} = Vout+1V for nominal V_{OUT}

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Application Information

Enable / Shutdown

The TS9007 comes with and active-high enable pin that allows the regulator to be enabled. Forcing the enable pin low disables the regulator and puts it into the shutdown mode. This pin cannot be left floating as it may cause an undetermined state.

Input / Output Capacitor

It is recommended to use a 0.47uF capacitor on the TS9007 input and a 0.47uF capacitor on the output. For high regulation performance, larger input capacitor values and lower ESRs provide better noise rejection and line-transient response. The output noise, load-transient response, stability, and power-supply rejection can be improved by using large output capacitors. Low ESR ceramic capacitors provide optimal performance and save space.

Power Supply Rejection and Transient Response

The PSRR and transient response can be improved by increasing the values of the input and output bypass capacitors, and through passive filtering techniques

Function Description

Description

The TS9007 is an ultra-low-noise, low-quiescent current, low-dropout linear regulator. It is supplied in a SOT-25 package for difference applications. This device can supply loads up to 300mA. As shown in the functional block diagram, the TS9007 consists of a reference and noise bypass circuit, error amplifier, output drive transistor, internal feedback voltage divider, thermal sensor, and short circuit current limiter. The internal reference is connected to the error amplifier's inverting input. The error amplifier compares this reference with the feedback voltage and amplifies the difference. If the feedback voltage is lower than the reference voltage, the pass=transistor gate is pulled low. This allows more current to pass to the output and increases the output voltage.

Stability

The TS9007 is a high performance LDO emphasizing stability with low output capacitance. It is able to maintain stability with an output capacitor can also be increased to optimize performance. The TS9007 will remain stable and in regulation with no load, unlike many other voltage regulators.

Internal P-Channel Pass Transistor

The TS9007 features a low impedance P-channel MOSFET pass transistor. This provides several advantages over similar designs using a PNP pass transistor, including low operating power and longer battery life. The TS9007 consumes only $90\mu A$ of quiescent current under most conditions.

Output Short-Circuit Current Limit

The TS9007 includes a current limiter, which monitors and controls the pass transistor's gage voltage, limiting the output current to about 200mA, for example, in a short-circuit output situation.

<u>Shutdown</u>

The TS9007 also features a low-power active shutdown mode. It has a switch that turns off the device when disabled. This allows the output capacitor and load to discharge and de-energize the load. In the shutdown mode, the internal functional blocks, such as voltage reference and the error amplifier, are turned off completely, and the quiescent current is less than $1\mu A$.



TS9007 300mA Low Noise CMOS LDO



Function Description (Continue)

Thermal Protection Shutdown

The thermal protection shutdown function protects the device from operating in over temperature condition. When the junction temperature exceeds $+160^{\circ}$ C, the thermal sensor signals the shutdown logic, turning off the pass transistor and allowing the IC to tool down. The thermal sensor turns the pass transistor on again after the IC's junction temperature drops to $+140^{\circ}$ C.

Soft-Start Circuitry

The TS9007 includes a soft-start circuitry to limit inrush current at turn-on. During power up, the output capacitor and output load are charged with a reduce output current. Shortly after the initial power up, the soft-start feature is terminated and normal operation is resumed.



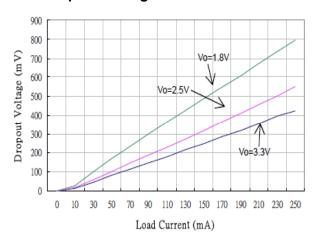
TS9007

300mA Low Noise CMOS LDO

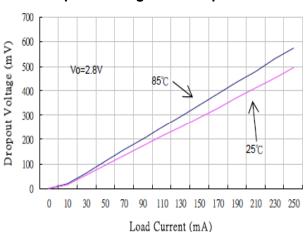


Electrical Characteristics Curve

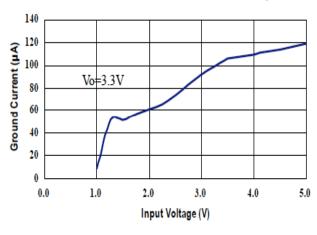
Dropout Voltage vs. Load Current



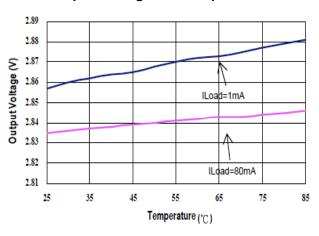
Dropout Voltage vs. Temperature



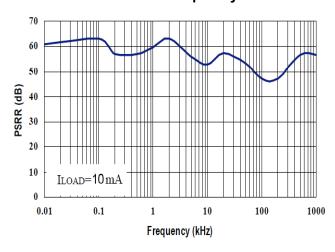
Ground Current vs. Input Voltage



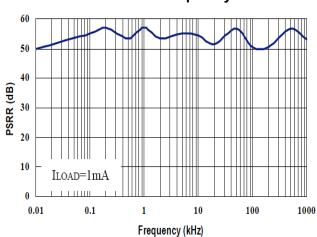
Output Voltage vs. Temperature



PSRR vs. Frequency



PSRR vs. Frequency

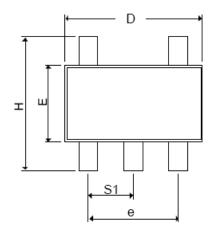


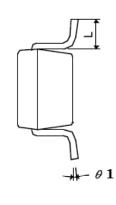






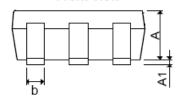
SOT-25 Mechanical Drawing



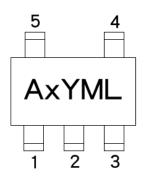


SOT-25 DIMENSION					
DIM	MILLIMETERS		INCHES		
DIIVI	MIN	MAX	MIN	MAX.	
A+A1	0.09	1.25	0.0354	0.0492	
В	0.30	0.50	0.0118	0.0197	
С	0.09	0.25	0.0035	0.0098	
D	2.70	3.10	0.1063	0.1220	
Е	1.40	1.80	0.0551	0.0709	
Е	1.90 BSC		0.0748 BSC		
Н	2.40	3.00	0.09449	0.1181	
L	0.35 BSC		0.0138 BSC		
θ1	0°	10°	0°	10°	
S1	0.95 BSC		0.0374 BSC		

Front View



Marking Diagram



A = Device Code

X = Fixed Output Voltage Code 1=1.2V, A=1.5V, D=1.8V, K=2.5V, M=2.7V, N=2.8V, O=2.9V P=3.0V, S=3.3V

Y = Year Code

M = Month Code

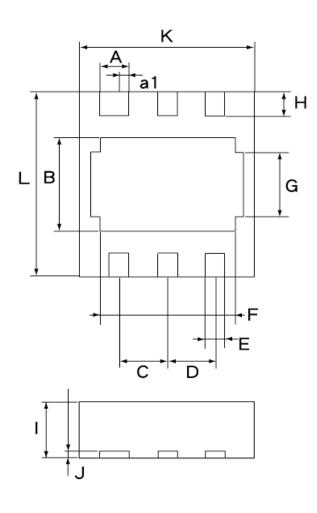
(A=Jan, B=Feb, C=Mar, D=Apl, E=May, F=Jun, G=Jul, H=Aug, I=Sep, J=Oct, K=Nov, L=Dec)

L = Lot Code



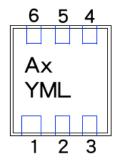


DFN 2x2 Mechanical Drawing



DFN 2x2 DIMENSION					
DIM	MILLIMETERS		INCHES		
ואווט	MIN	MAX	MIN	MAX	
Α	0.25	0.35	0.0098	0.0138	
a1	0.10 (typ)		0.0039 (typ)		
В	0.90	1.10	0.0354	0.0433	
C	0.50 (typ)		0.0197 (typ)		
D	0.50 (typ)		0.0197 (typ)		
Е	0.15	0.25	0.0059	0.0098	
F	1.30	1.50	0.0512	0.0591	
G	0.67	0.73	0.0264	0.0287	
Н	0.20	0.30	0.0079	0.0118	
	I 0.60 (MAX.)		0.0236 (MAX.)		
J	0.07 (MAX.)		0.0028 (MAX.)		
K	1.75	1.85	0.0689	0.0728	
L	1.95	2.05	0.0768	0.0807	

Marking Diagram



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(**A**=Jan, **B**=Feb, **C**=Mar, **D**=Apl, **E**=May, **F**=Jun, **G**=Jul, **H**=Aug, **I**=Sep, **J**=Oct, **K**=Nov, **L**=Dec)

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